2SD1274, 2SD1274A, 2SD1274B

Silicon NPN triple diffusion planar type

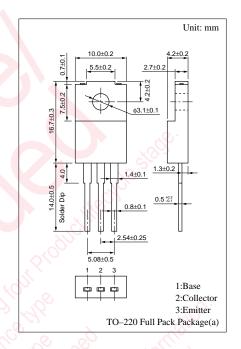
For power amplification

Features

- High collector to base voltage V_{CBO}
- High-speed switching
- Full-pack package which can be installed to the heat sink with one screw

Absolute Maximum Ratings (T_C=25°C)

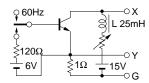
Parameter		Symbol	Ratings	Unit		
Collector to base voltage	2SD1274		150			
	2SD1274A	V_{CBO}	200	V		
	2SD1274B		250			
Collector to emitter voltage	2SD1274		150	V		
	2SD1274A	V _{CES}	200			
	2SD1274B		250			
Collector to emitter voltage		V _{CEO}	80	V		
Emitter to base voltage		V_{EBO}	6	V		
Collector current		$I_{\rm C}$	5	Α		
Collector power	T _C =25°C	D	40	657		
dissipation	Ta=25°C	P_{C}	2	O W		
Junction temperature		T _j	150	°C		
Storage temperature		$T_{\rm stg}$	-55 to +150	% .C		



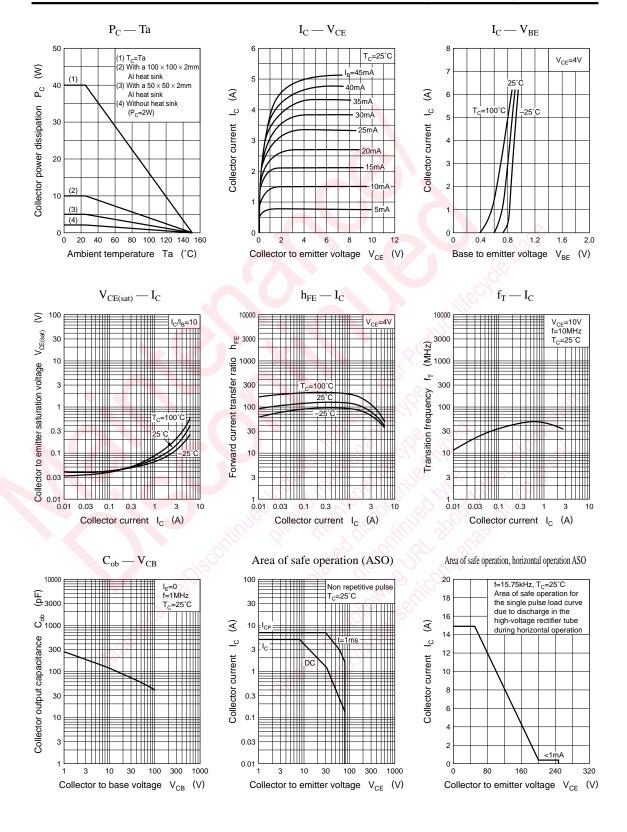
Electrical Characteristics (T_C=25°C)

Parameter		Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	2SD1274	I _{CBO}	$V_{CB} = 150V, I_{E} = 0$			1	mA
	2SD1274A		$V_{CB} = 200V, I_{E} = 0$			1	
	2SD1274B		$V_{CB} = 250V, I_{E} = 0$			1	
Collector to emitter voltage		V _{CEO(sus)} *	$I_C = 0.2A, L = 25mH$	80			V
Emitter to base voltage		V _{EBO}	$I_E = 1 \text{mA}, I_C = 0$	6			V
Forward current transfer ratio		h _{FE}	$V_{CE} = 4V, I_C = 5A$	14			
Base to emitter voltage V		V _{BE}	$V_{CE} = 4V, I_C = 5A$			1.5	V
Collector to emitter saturation voltage V _{CE}		V _{CE(sat)}	$I_C = 5A, I_B = 1A$			1.6	V
Transition frequency		f_T	$V_{CE} = 10V, I_{C} = 0.5A, f = 10MHz$		40		MHz
Fall time		t _f	$I_C = 5A$, $I_{B1} = 0.8A$, $V_{EB} = -5V$			1	μs

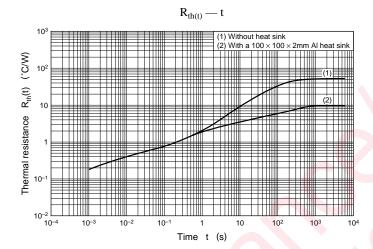








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